

DOCKET NO. : LIN 13-38

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Wen Lin, et al.

For:

SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE  
MATCHING LAYER AND A METHOD OF MANUFACTURE  
THEREFOR

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence, including the attachments listed, is being deposited with the United States Postal Service, Express Mail Post Office to Addressee, Receipt No. **EV 312641086US** in an envelope addressed to Commissioner of Patents, Alexandria, VA 22313-1450, on the date shown below.

**3.31.2004** *Elizabeth Schumacher*  
Date of Mailing Signature of Person mailing

Sir:

PRELIMINARY AMENDMENT

Before examination of the above-identified application, please amend it as follows:

IN THE SPECIFICATION

Please amend the specification by inserting before the first line the sentence:

--This Application is a Divisional of prior Application Serial No. 10/003,873 filed on October 24, 2001, currently pending, to Wen Lin, et al.. The above-listed Application is commonly assigned with the present invention and is incorporated herein by reference as if reproduced herein in its entirety under Rule 1.53(b).--